

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

## 2. Features and benefits

- Good blocking voltage capability
- High thermal cycling performance
- Isolated mounting base package
- · Planar passivated for voltage ruggedness and reliability
- Very high current surge capability

## 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

## 4. Quick reference data

Symbol	Parameter	Conditions	1	Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	-	400	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_h \leq 43 \degree C$	-	-	-	13	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_h \le 43 \text{ °C}$ ; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	-	20	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	-	200	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	-	-	220	A
Tj	junction temperature		-	-	-	125	°C
Static chara	acteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	3	32	mA
Dynamic ch	aracteristics				1	1	

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 268 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); gate open circuit; exponential waveform; Fig. 12	200	300	-	V/µs

## 5. Pinning information

	. Pinning in		Circulified extiline	Crenhia avrahal
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	A - D- K
2	Α	anode		G sym037
3	G	gate		
mb	n.c.	mounting base; isolated		
			1 2 3 TO-220F (SOT186A)	

## 6. Ordering information

Table 3.	Orderina	information
	e a e i i i g	

Type number	Package				
	Name	Description	Version		
BT152X-400R	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A		



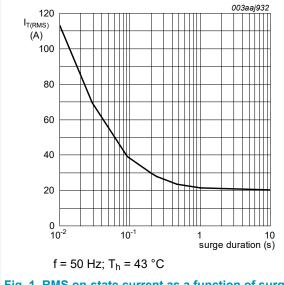
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## 7. Limiting values

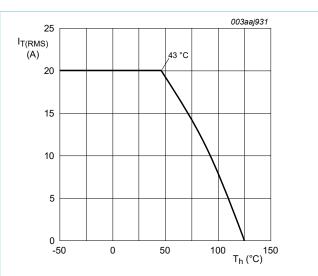
#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	400	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	400	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>h</sub> ≤ 43 °C	-	13	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_h \le 43$ °C; <u>Fig. 1; Fig. 2;</u> Fig. 3	-	20	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	200	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	220	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	200	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_T = 50 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	200	A/µs
I <sub>GM</sub>	peak gate current		-	5	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	125	°C

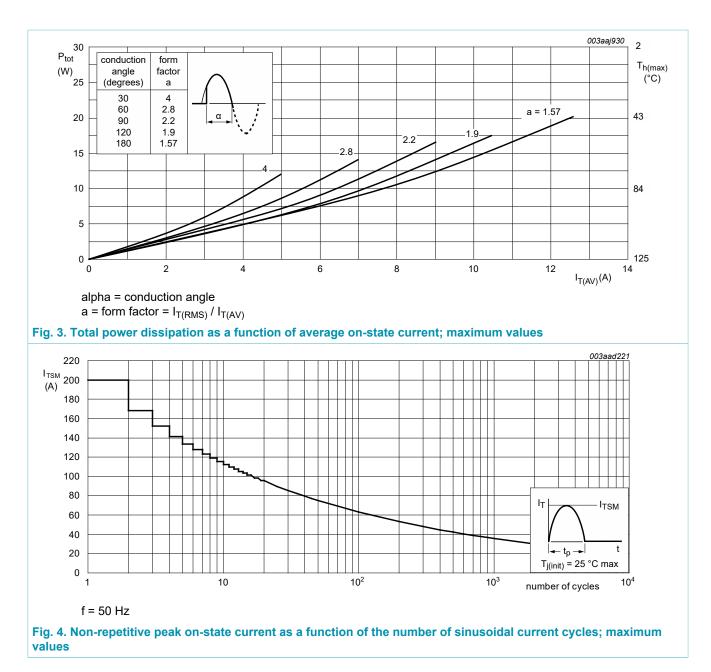








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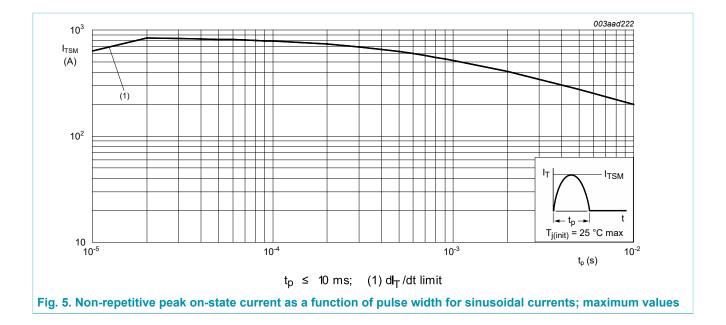


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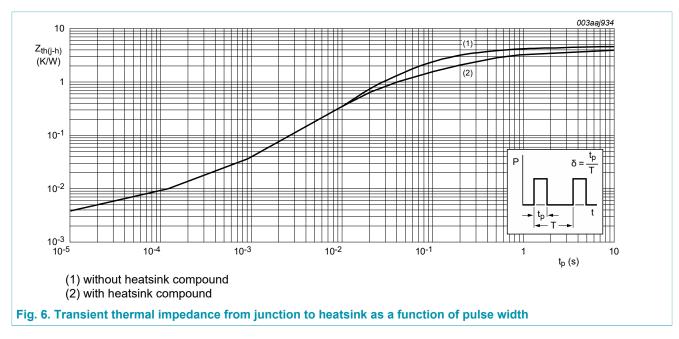


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### 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-h)</sub>	thermal resistance	with heatsink compound; Fig. 6	-	-	4	K/W
	from junction to heatsink	without heatsink compound; Fig. 6	-	-	4.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air		-	55	-	K/W



## 9. Isolation characteristics

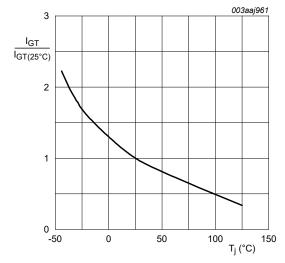
#### Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; T <sub>h</sub> = 25 °C	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	from anode to external heatsink; f = 1 MHz; T <sub>h</sub> = 25 °C	-	10	-	pF

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### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		l			
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	3	32	mA
IL .	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	25	80	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	15	60	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 40 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 11	-	0.6	1	V
		$V_D$ = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 11	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 400 V; T <sub>j</sub> = 125 °C	-	0.2	1	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 400 V; T <sub>j</sub> = 125 °C	-	0.2	1	mA
Dynamic ch	naracteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 268 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); gate open circuit; exponential waveform; Fig. 12	200	300	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 40 A; V <sub>D</sub> = 400 V; I <sub>G</sub> = 0.1 A; dI <sub>G</sub> / dt = 5 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
tq	commutated turn-off time		-	70	-	μs





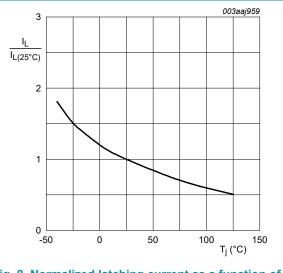
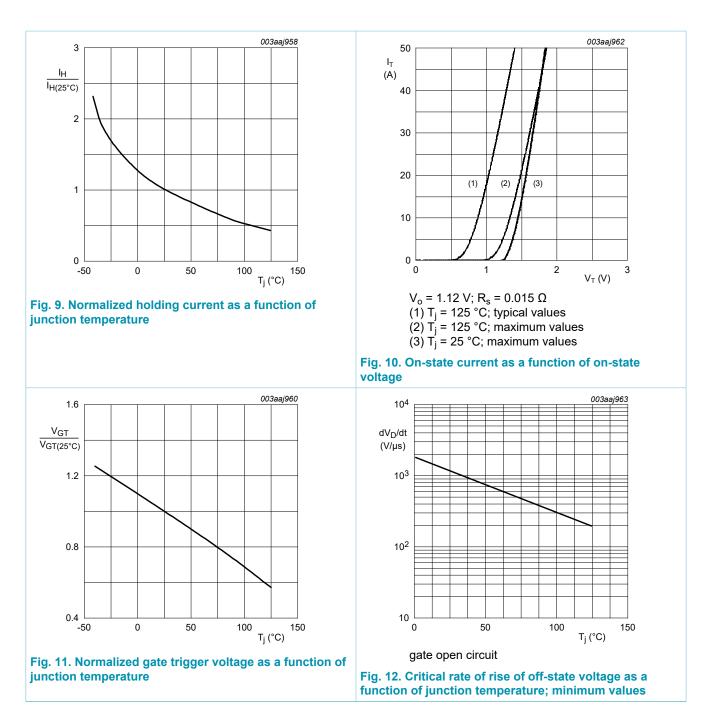


Fig. 8. Normalized latching current as a function of junction temperature

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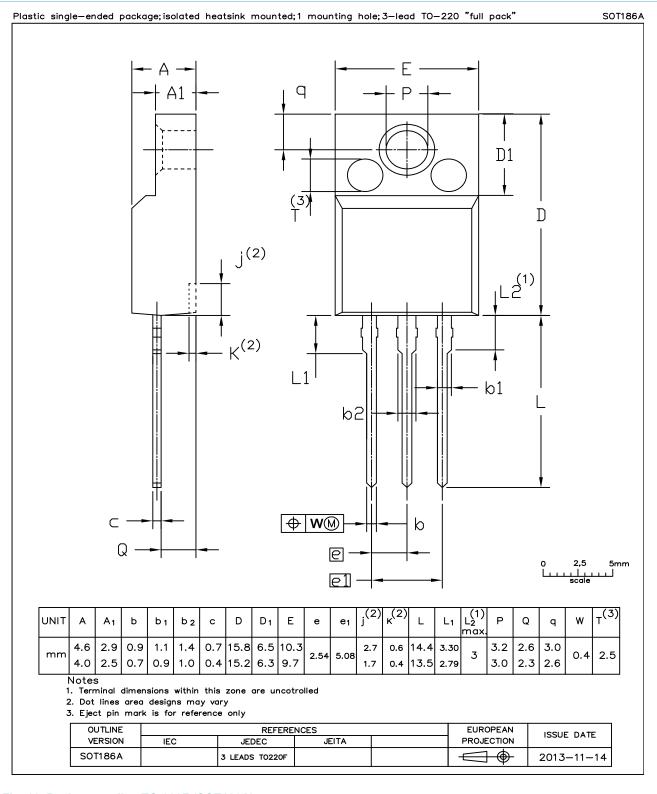


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## 11. Package outline



#### Fig. 13. Package outline TO-220F (SOT186A)

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## 12. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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